Philips Components-Signetics

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| Memory Produ | ıcts |

82S137 4K-bit TTL bipolar PROM

DESCRIPTION

The 82S137 is field programmable, which means that custom patterns are immediately available by following the Signetics Generic I fusing procedure. The 82S137 is supplied with all outputs at logical Low. Outputs are programmed to a logic High level at any specified address by fusing the Ni-Cr link matrix.

This device includes on-chip decoding and 2 Chip Enable inputs for ease of memory expansion. It features 3-State outputs for optimization of word expansion in bused organizations.

Ordering information can be found on the following page.

The 82S137 device is also processed to military requirements for operation over the military temperature range, for specifications and ordering information consult the Signetics Military Data Handbook.

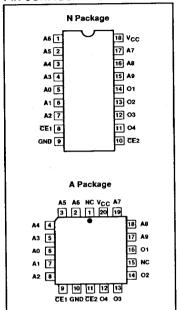
FEATURES

- · Address access time: 60ns max
- Power dissipation: 0.13mW/bit typ
- Input loading: -100µA max
- On-chip address decoding
- No separate fusing pins
- Unprogrammed outputs are Low level
- Fully TTL compatible
- Two Chip Enable inputs
- Outputs: 3-State

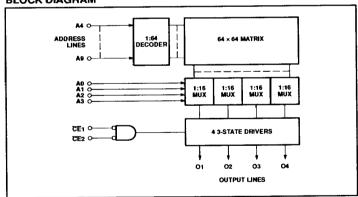
APPLICATIONS

- Sequential controllers
- Control store
- Random logic
- Code conversion

PIN CONFIGURATIONS



BLOCK DIAGRAM



4K-bit TTL bipolar PROM (1024 \times 4)

82S137

ORDERING INFORMATION

| DESCRIPTION | ORDER CODE |
|---|------------|
| 18-Pin Plastic Dual-In-Line 300mil-wide | N82S137 N |
| 20-Pin Plastic Leaded Chip Carrier 350mil-square | N82S137 A |

ABSOLUTE MAXIMUM RATINGS

| SYMBOL | PARAMETER | RATING | UNIT | |
|------------------|-----------------------------|-------------|-----------------|--|
| V _{CC} | Supply voltage | +7.0 | V _{DC} | |
| V _{IN} | Input voltage | +5.5 | V _{DC} | |
| Vo | Output voltage Off-State | +5.5 | V _{DC} | |
| T _{amb} | Operating temperature range | 0 to +75 | % | |
| T _{stq} | Storage temperature range | -65 to +150 | °C | |

DC ELECTRICAL CHARACTERISTICS 0°C < Torrel < +75°C, 4.75V < Voc < 5.25V

| | | | LIMITS | | | UNIT |
|------------------|----------------------------|---|--------|----------------------|------|------|
| SYMBOL PARAMETER | | TEST CONDITIONS ^{1,2} | Min | Typ ³ Max | | |
| input volt | age | | | | | |
| V _{IL} | Low | | | | 0.8 | ٧ |
| VIH | High | | 2.0 | 1 | | ٧ |
| V _{IC} | Clamp | I _{IN} = -12mA | 1 | | -1.2 | ٧ |
| Output vo | ltage | | | | | |
| | | CE1,2 = Low | | | | |
| V_{OL} | Low | I _{OUT} = 16mA | | | 0.45 | ٧ |
| VOH | High . | I _{OUT} = -2mA | 2.4 | | | V |
| Input cur | ent | | | | | |
| I _{IL} | Low | V _{IN} = 0.45V | | | -100 | μА |
| I _{IH} | High | $V_{1N} = 5.5V$ | | | 40 | μΑ |
| Output cu | irrent | | | | | |
| loz | Hi-Z state | CE1,2 = High, V _{OUT} = 0.5V | | | -40 | μΑ |
| | | $\overline{CE}1,2 = High, V_{OUT} = 5.5V$ | | | 40 | μA |
| los | Short circuit ⁴ | CE1,2 = Low, V _{OUT} = 0V, High stored -15 -70 | | -70 | mA | |
| Supply co | urrent ⁵ | | | | | |
| Icc | | V _{CC} = 5.25V | | | 140 | mA |
| Capacita | nce | | | | | |
| | | CE1,2 = High, V _{CC} = 5.0V | | | | |
| CIN | Input | $V_{1N} = 2.0V$ | 1 | 5 | | рF |
| COUT | Output | V _{OUT} = 2.0V | - 1 | 8 | | pF |

NOTES:

- 1. Positive current is defined as into the terminal referenced.
- 2. All voltages with respect to network ground.
- Typical values are at V_{CC} = 5V, T_{amb} = +25°C.
 Duration of short circuit should not exceed 1 second.
- 5. Measured with all inputs grounded and all outputs open.

AC ELECTRICAL CHARACTERISTICS

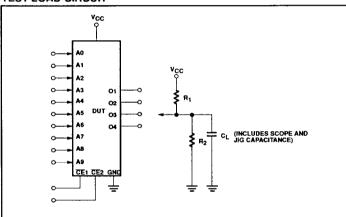
 $R_1 = 270\Omega$, $R_2 = 600\Omega$, $C_L = 30 pF$, $0^{\circ}C \le T_{amb} \le +75^{\circ}C$, $4.75V \le V_{CC} \le 5.25V$

| SYMBOL | PARAMETER | то | | LIMITS | | | |
|-----------------|-----------|---------------------|--------------|--------|------|-----|------|
| | | | FROM | Min | Typ1 | Max | UNIT |
| Access time | 2 | | | | | | |
| t _{AA} | | Output | Address | | 40 | 60 | пѕ |
| t _{CE} | | Output [*] | Chip Enable | | 25 | 30 | ns |
| Disable time | 3 | | | | | | |
| t _{CD} | | Output | Chip Disable | | 25 | 30 | ns |

NOTES:

- 1. Typical values are at V_{CC} = 5V, T_{amb} = +25°C. 2. Tested at an address cycle time of 1 μ s. 3. Measured at a delta of 0.5V from Logic Level with R_1 = 750 Ω , R_2 = 750 Ω , C_L = 5pF.

TEST LOAD CIRCUIT



VOLTAGE WAVEFORMS

